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ISL22346
Quad Digitally Controlled Potentiometers (XDCP™)

Low Noise, Low Power I²C™ Bus, 128 Taps

The ISL22346 integrates four digitally controlled potentiometers (DCP) and non-volatile memory on a monolithic CMOS integrated circuit.
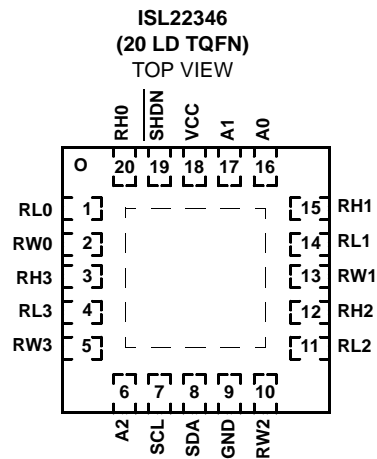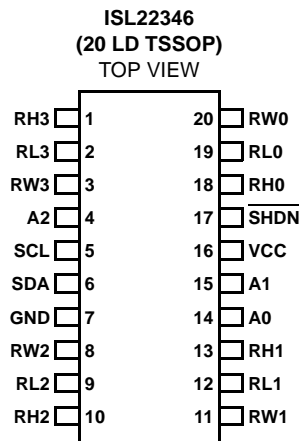
The digitally controlled potentiometers are implemented with a combination of resistor elements and CMOS switches. The position of the wipers are controlled by the user through the I²C bus interface. Each potentiometer has an associated volatile Wiper Register (WR) and a non-volatile Initial Value Register (IVR) that can be directly written to and read by the user. The contents of the WR controls the position of the wiper. At power-up the device recalls the contents of the two DCP's IVR to the corresponding WRs.

The DCPs can be used as a three-terminal potentiometers or as a two-terminal variable resistors in a wide variety of applications including control, parameter adjustments, and signal processing.

Features

- Four potentiometers in one package

- 128 resistor taps

- I²C serial interface
  - Three address pins, up to eight devices/bus

- Non-volatile storage of wiper position

- Wiper resistance: 70Ω typical @ V_{CC} = 3.3V

- Shutdown mode

- Shutdown current 5µA max

- Power supply: 2.7V to 5.5V

- 50kΩ or 10kΩ total resistance

- High reliability
  - Endurance: 1,000,000 data changes per bit per register
  - Register data retention: 50 years @ T $\leq$ +55°C

- 20 Ld TSSOP or 20 Ld TQFN package

- Pb-free (RoHS compliant)

Pinouts

ISL22346
(20 LD TSSOP)
TOP VIEW

RH3	1		20	RW0
RL3	2		19	RL0
RW3	3		18	RH0
A2	4		17	SHDN
SCL	5		16	VCC
SDA	6		15	A1
GND	7		14	A0
RW2	8		13	RH1
RL2	9		12	RL1
RH2	10		11	RW1

ISL22346
(20 LD TQFN)
TOP VIEW

Top pins: RH0 (20), SHDN (19), VCC (18), A1 (17), A0 (16)

RL0	1	15	RH1
RW0	2	14	RL1
RH3	3	13	RW1
RL3	4	12	RH2
RW3	5	11	RL2

Bottom pins: A2 (6), SCL (7), SDA (8), GND (9), RW2 (10)

ISL22346

Ordering Information

PART NUMBER (Note)	PART MARKING	RESISTANCE OPTION (kΩ)	TEMP. RANGE (°C)	PACKAGE (Pb-free)	PKG. DWG. #
ISL22346UFV20Z*	22346 UFVZ	50	-40 to +125	20 Ld TSSOP	M20.173
ISL22346UFRT20Z*	223 46UFZ	50	-40 to +125	20 Ld 4x4 TQFN	L20.4x4A
ISL22346WFV20Z*	22346 WFVZ	10	-40 to +125	20 Ld TSSOP	M20.173
ISL22346WFRT20Z*	223 46WFZ	10	-40 to +125	20 Ld 4x4 TQFN	L20.4x4A

*Add "-TK" suffix for tape and reel. Please refer to TB347 for details on reel specifications.

NOTE: These Intersil Pb-free plastic packaged products employ special Pb-free material sets, molding compounds/die attach materials, and 100% matte tin plate plus anneal (e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations). Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.

Block Diagram
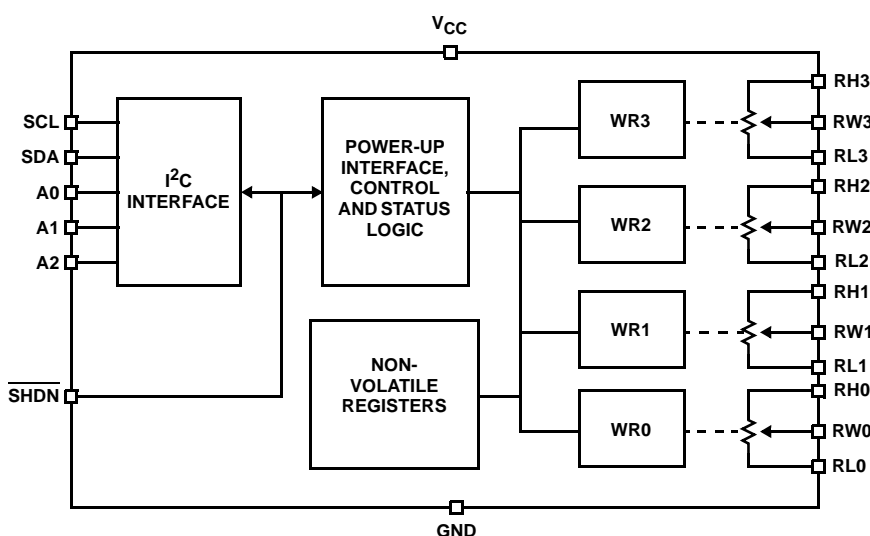
Pin Descriptions

TSSOP PIN NUMBER	TQFN PIN NUMBER	PIN NAME	DESCRIPTION
1	3	RH3	"High" terminal of DCP3
2	4	RL3	"Low" terminal of DCP3
3	5	RW3	"Wiper" terminal of DCP3
4	6	A2	Device address input for the I^2C interface
5	7	SCL	Open drain I^2C interface clock input
6	8	SDA	Open drain Serial data I/O for the I^2C interface
7	9	GND	Device ground pin
8	10	RW2	"Wiper" terminal of DCP2
9	11	RL2	"Low" terminal of DCP2
10	12	RH2	"High" terminal of DCP2
11	13	RW1	"Wiper" terminal of DCP1
12	14	RL1	"Low" terminal of DCP1
13	15	RH1	"High" terminal of DCP1
14	16	A0	Device address input for the I^2C interface

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Pin Descriptions (Continued)

TSSOP PIN NUMBER	TQFN PIN NUMBER	PIN NAME	DESCRIPTION
15	17	A1	Device address input for the I^2C interface
16	18	VCC	Power supply pin
17	19	$\overline{SHDN}$	Shutdown active low input
18	20	RH0	"High" terminal of DCP0
19	1	RL0	"Low" terminal of DCP0
20	2	RW0	"Wiper" terminal of DCP0
	EPAD*		Exposed Die Pad internally connected to GND

*Note: PCB thermal land for QFN EPAD should be connected to GND plane or left floating. For more information refer to http://www.intersil.com/data/tb/TB389.pdf

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Absolute Maximum Ratings

Storage Temperature . . . .-65°C to +150°C
Voltage at any Digital Interface Pin
   with Respect to GND . . . . -0.3V to V_{CC} + 0.3
V_{CC} . . . .-0.3V to +6V
Voltage at any DCP Pin with Respect to GND. . . . . . . -0.3V to V_{CC}
I_W (10s) . . . . ±6mA
Latchup (Note 4) . . . . Class II, Level B @ +125°C
ESD Ratings
   Human Body Model 2.5kV
   Machine Model. 350V

Thermal Information

Thermal Resistance (Typical)	θ_{JA} (°C/W)	θ_{JC} (°C/W)
20 Lead TSSOP (Note 1)	95	N/A
20 Lead TQFN (Notes 2, 3)	40	3.0

Maximum Junction Temperature (Plastic Package). . . . .+150°C
Pb-free Reflow Profile . . . . .see link below
   http://www.intersil.com/pbfree/Pb-FreeReflow.asp

Recommended Operating Conditions

Temperature Range (Extended Industrial). . . . .-40°C to +125°C
V_{CC} . . . . 2.7V to 5.5V
Power Rating 15mW
Wiper Current . . . .±3.0mA

CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.

NOTES:

1. θ_{JA} is measured with the component mounted on a high effective thermal conductivity test board in free air. See Tech Brief TB379 for details.

2. θ_{JA} is measured in free air with the component mounted on a high effective thermal conductivity test board with "direct attach" features. See Tech Brief TB379.

3. For θ_{JC}, the "case temp" location is the center of the exposed metal pad on the package underside.

4. Jedec Class II pulse conditions and failure criterion used. Level B exceptions are: using a max positive pulse of 6.5V on the $\overline{\text{SHDN}}$ pin, and using a max negative pulse of -0.8V for all pins.

Analog Specifications
Over recommended operating conditions, unless otherwise stated.

SYMBOL	PARAMETER	TEST CONDITIONS	MIN (Note 21)	TYP (Note 5)	MAX (Note 21)	UNIT
R_{TOTAL}	R_H to R_L Resistance	W option		10		kΩ
		U option		50		kΩ
	R_H to R_L Resistance Tolerance	W and U option	-20		+20	%
	End-to-End Temperature Coefficient	W option		±50		ppm/°C (Note 18)
		U option		±80		ppm/°C (Note 18)
V_{RH}, V_{RL}	V_{RH} and V_{RL} Terminal Voltages	V_{RH} and V_{RL} to GND	0		V_{CC}	V
R_W	Wiper Resistance	V_{CC} = 3.3V, wiper current = V_{CC}/R_{TOTAL}		70	200	Ω
C_H/C_L/C_W (Note 20)	Potentiometer Capacitance			10/10/25		pF
I_{LkgDCP}	Leakage on DCP Pins	Voltage at pin from GND to V_{CC}		0.1	1	µA
VOLTAGE DIVIDER MODE (0V @ R_Li; V_{CC} @ R_Hi; measured at R_Wi, unloaded; i = 0, 1, 2, or 3)						
INL (Note 10)	Integral Non-linearity	Monotonic over all tap positions	-1		1	LSB (Note 6)
DNL (Note 9)	Differential Non-linearity	Monotonic over all tap positions	-0.5		0.5	LSB (Note 6)
ZSerror (Note 7)	Zero-scale Error	W option	0	1	5	LSB (Note 6)
		U option	0	0.5	2	
FSerror (Note 8)	Full-scale error	W option	-5	-1	0	LSB (Note 6)
		U option	-2	-1	0	
V_{MATCH} (Note 11)	DCP to DCP Matching	Any two DCPs at same tap position, same voltage at all R_H terminals, and same voltage at all R_L terminals	-2		2	LSB (Note 6)

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Analog Specifications   Over recommended operating conditions, unless otherwise stated. **(Continued)**

SYMBOL	PARAMETER	TEST CONDITIONS	MIN (Note 21)	TYP (Note 5)	MAX (Note 21)	UNIT
TC_V (Note 12)	Ratiometric Temperature Coefficient	DCP register set to 40 hex		±4		ppm/°C
RESISTOR MODE (Measurements between R_Wi and R_Li with R_Hi not connected, or between R_Wi and R_Hi with R_Li not connected. i = 0, 1, 2 or 3)						
RINL (Note 16)	Integral Non-linearity	DCP register set between 10h and 7Fh; monotonic over all tap positions	-1		1	MI (Note 13)
RDNL (Note 15)	Differential Non-linearity	DCP register set between 10h and 7Fh; monotonic over all tap positions, W option	-1		1	MI (Note 13)
		DCP register set between 10h and 7Fh; monotonic over all tap positions, U option	-0.5		0.5	MI (Note 13)
Roffset (Note 14)	Offset	W option	0	1	5	MI (Note 13)
		U option	0	0.5	2	MI (Note 13)
R_{MATCH} (Note 17)	DCP to DCP Matching	Any two DCPs at the same tap position with the same terminal voltages	-2		2	MI (Note 13)

Operating Specifications   Over the recommended operating conditions, unless otherwise specified.

SYMBOL	PARAMETER	TEST CONDITIONS	MIN (Note 21)	TYP (Note 5)	MAX (Note 21)	UNIT
I_{CC1}	V_{CC} Supply Current (Volatile Write/Read)	f_{SCL} = 400kHz; SDA = Open; (for I²C, active, read and write states)			0.5	mA
I_{CC2}	V_{CC} Supply Current (Non-volatile Write/Read)	f_{SCL} = 400kHz; SDA = Open; (for I²C, active, read and write states)			3	mA
I_{SB}	V_{CC} Current (Standby)	V_{CC} = +5.5V @ +85°C, I²C interface in standby state			5	µA
		V_{CC} = +5.5V @ +125°C, I²C interface in standby state			7	µA
		V_{CC} = +3.6V @ +85°C, I²C interface in standby state			3	µA
		V_{CC} = +3.6V @ +125°C, I²C interface in standby state			5	µA
I_{SD}	V_{CC} Current (Shutdown)	V_{CC} = +5.5V @ +85°C, I²C interface in standby state			3	µA
		V_{CC} = +5.5V @ +125°C, I²C interface in standby state			5	µA
		V_{CC} = +3.6V @ +85°C, I²C interface in standby state			2	µA
		V_{CC} = +3.6V @ +125°C, I²C interface in standby state			4	µA
I_{LkgDig}	Leakage Current, at Pins A0, A1, A2, SHDN, SDA and SCL	Voltage at pin from GND to V_{CC}	-1		1	µA
t_{WRT} (Note 20)	DCP Wiper Response Time	SCL falling edge of last bit of DCP data byte to wiper new position		1.5		µs
$t_{ShdnRec}$ (Note 20)	DCP Recall Time from Shutdown Mode	From rising edge of SHDN signal to wiper stored position and RH connection		1.5		µs
		SCL falling edge of last bit of ACR data byte to wiper stored position and RH connection		1.5		µs
Vpor	Power-on Recall Voltage	Minimum V_{CC} at which memory recall occurs	2.0		2.6	V

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Operating Specifications Over the recommended operating conditions, unless otherwise specified. **(Continued)**

| SYMBOL	PARAMETER	TEST CONDITIONS	MIN (Note 21)	TYP (Note 5)	MAX (Note 21)	UNIT
$V_{CC}Ramp$	V_{CC} Ramp Rate		0.2			V/ms
t_D	Power-up Delay	V_{CC} above Vpor, to DCP Initial Value Register recall completed, and I^{2}C Interface in standby state			3	ms
EEPROM SPECIFICATION						
	EEPROM Endurance		1,000,000			Cycles
	EEPROM Retention	Temperature T $\leq$ +55°C	50			Years
t_{WC} (Note 19)	Non-volatile Write Cycle Time			12	20	ms
SERIAL INTERFACE SPECIFICATIONS						
V_{IL}	A2, A1, A0, $\overline{SHDN}$, SDA, and SCL Input Buffer LOW Voltage		-0.3		$0.3*V_{CC}$	V
V_{IH}	A2, A1, A0, $\overline{SHDN}$, SDA, and SCL Input Buffer HIGH Voltage		$0.7*V_{CC}$		V_{CC} + 0.3	V
Hysteresis	SDA and SCL Input Buffer Hysteresis		$0.05*V_{CC}$			V
V_{OL}	SDA Output Buffer LOW Voltage, Sinking 4mA		0		0.4	V
Cpin (Note 20)	A2, A1, A0, $\overline{SHDN}$, SDA, and SCL Pin Capacitance			10		pF
f_{SCL}	SCL Frequency				400	kHz
t_{sp}	Pulse Width Suppression Time at SDA and SCL Inputs	Any pulse narrower than the max spec is suppressed			50	ns
t_{AA}	SCL Falling Edge to SDA Output Data Valid	SCL falling edge crossing 30% of V_{CC}, until SDA exits the 30% to 70% of V_{CC} window			900	ns
t_{BUF}	Time the Bus Must be Free Before the Start of a New Transmission	SDA crossing 70% of V_{CC} during a STOP condition, to SDA crossing 70% of V_{CC} during the following START condition	1300			ns
t_{LOW}	Clock LOW Time	Measured at the 30% of V_{CC} crossing	1300			ns
t_{HIGH}	Clock HIGH Time	Measured at the 70% of V_{CC} crossing	600			ns
$t_{SU:STA}$	START Condition Setup Time	SCL rising edge to SDA falling edge; both crossing 70% of V_{CC}	600			ns
$t_{HD:STA}$	START Condition Hold Time	From SDA falling edge crossing 30% of V_{CC} to SCL falling edge crossing 70% of V_{CC}	600			ns
$t_{SU:DAT}$	Input Data Setup Time	From SDA exiting the 30% to 70% of V_{CC} window, to SCL rising edge crossing 30% of V_{CC}	100			ns
$t_{HD:DAT}$	Input Data Hold Time	From SCL rising edge crossing 70% of V_{CC} to SDA entering the 30% to 70% of V_{CC} window	0			ns
$t_{SU:STO}$	STOP Condition Setup Time	From SCL rising edge crossing 70% of V_{CC}, to SDA rising edge crossing 30% of V_{CC}	600			ns
$t_{HD:STO}$	STOP Condition Hold Time for Read, or Volatile Only Write	From SDA rising edge to SCL falling edge; both crossing 70% of V_{CC}	1300			ns
t_{DH}	Output Data Hold Time	From SCL falling edge crossing 30% of V_{CC}, until SDA enters the 30% to 70% of V_{CC} window	0			ns
t_R	SDA and SCL Rise Time	From 30% to 70% of V_{CC}	20 + 0.1*Cb		250	ns

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Operating Specifications   Over the recommended operating conditions, unless otherwise specified. **(Continued)**

SYMBOL	PARAMETER	TEST CONDITIONS	MIN (Note 21)	TYP (Note 5)	MAX (Note 21)	UNIT
t_F	SDA and SCL Fall Time	From 70% to 30% of V_{CC}	20 + 0.1*Cb		250	ns
Cb	Capacitive Loading of SDA or SCL	Total on-chip and off-chip	10		400	pF
Rpu	SDA and SCL Bus Pull-up Resistor Off-chip	Maximum is determined by t_R and t_F For Cb = 400pF, max is about 2kΩ~2.5kΩ For Cb = 40pF, max is about 15kΩ~20kΩ	1			kΩ
$t_{SU:A}$	A2, A1 and A0 Setup Time	Before START condition	600			ns
$t_{HD:A}$	A2, A1 and A0 Hold Time	After STOP condition	600			ns

NOTES:

5. Typical values are for T_A = +25°C and 3.3V supply voltage.

6. LSB: $[V(R_W)_{127} - V(R_W)_0]/127$. $V(R_W)_{127}$ and $V(R_W)_0$ are $V(R_W)$ for the DCP register set to 7F hex and 00 hex respectively. LSB is the incremental voltage when changing from one tap to an adjacent tap.

7. ZS error = $V(RW)_0$/LSB.

8. FS error = $[V(RW)_{127} - V_{CC}]$/LSB.

9. DNL = $[V(RW)_i - V(RW)_{i-1}]$/LSB-1, for i = 1 to 127. i is the DCP register setting.

10. INL = $[V(RW)_i - i \cdot LSB - V(RW)_0]$/LSB for i = 1 to 127.

11. $V_{MATCH} = [V(RWx)_i - V(RWy)_i]$/LSB, for i = 1 to 127, x = 0 to 3 and y = 0 to 3.

12. $TC_V = \dfrac{Max(V(RW)_i) - Min(V(RW)_i)}{[Max(V(RW)_i) + Min(V(RW)_i)]/2} \times \dfrac{10^6}{+165°C}$ for i = 16 to 112 decimal, T = -40°C to +125°C. Max( ) is the maximum value of the wiper voltage and Min ( ) is the minimum value of the wiper voltage over the temperature range.

13. MI = $|RW_{127} - RW_0|$/127. RW_{127} and RW_0 are the measured resistances for the DCP register set to 7F hex and 00 hex respectively.

14. Roffset = RW_0/MI, when measuring between RW and RL.
    Roffset = RW_{127}/MI, when measuring between RW and RH.

15. RDNL = $(RW_i - RW_{i-1})$/MI - 1, for i = 16 to 127.

16. RINL = $[RW_i - (MI \cdot i) - RW_0]$/MI, for i = 16 to 127.

17. $R_{MATCH} = (RW_{i,x} - RW_{i,y})$/MI, for i = 1 to 127, x = 0 to 3 and y = 0 to 3.

18. $TC_R = \dfrac{[Max(Ri) - Min(Ri)]}{[Max(Ri) + Min(Ri)]/2} \times \dfrac{10^6}{+165°C}$ for i = 16 to 112, T = -40°C to +125°C. Max( ) is the maximum value of the resistance and Min ( ) is the minimum value of the resistance over the temperature range.

19. t_{WC} is the time from a valid STOP condition at the end of a Write sequence of I^2C serial interface, to the end of the self-timed internal non-volatile write cycle.

20. Limits should be considered typical and are not production tested.

21. Parameters with MIN and/or MAX limits are 100% tested at +25°C, unless otherwise specified. Temperature limits established by characterization and are not production tested.

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SDA vs SCL Timing
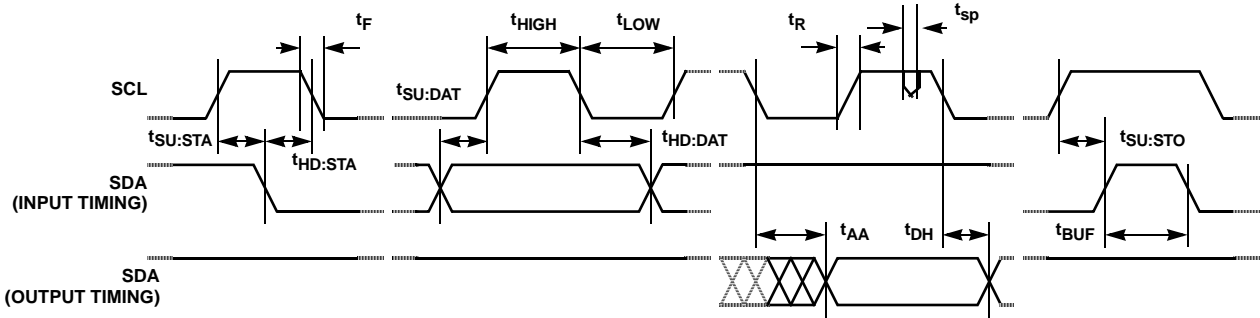
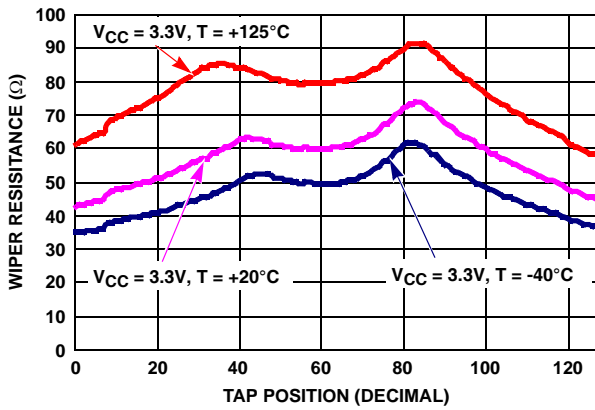### A0, A1, and A2 Pin Timing
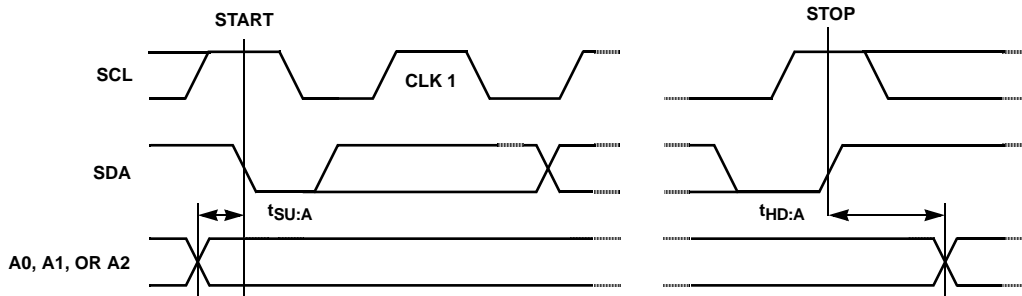
Typical Performance Curves

FIGURE 1. WIPER RESISTANCE vs TAP POSITION
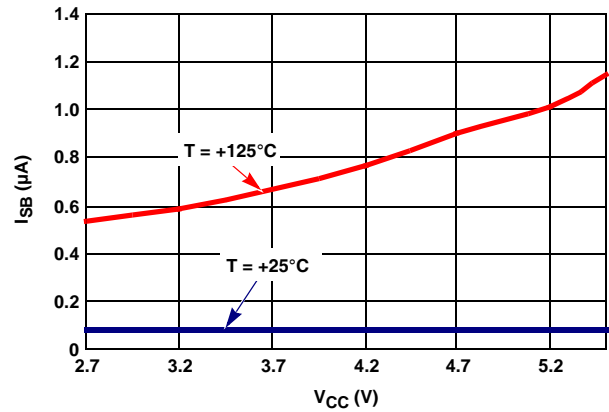[I(RW) = V_{CC}/R_{TOTAL}] FOR 10kΩ (W)

FIGURE 2. STANDBY I_{CC} vs V_{CC}

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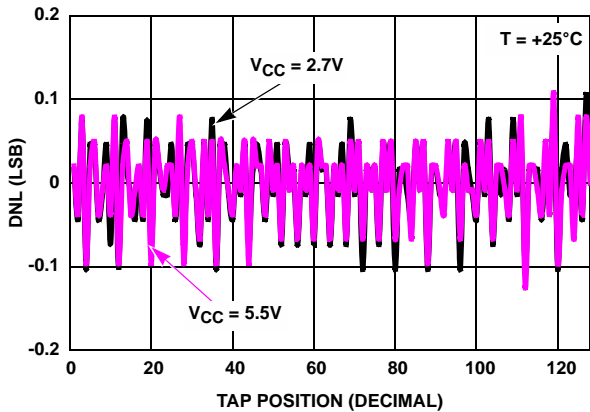## ISL22346

Typical Performance Curves (Continued)

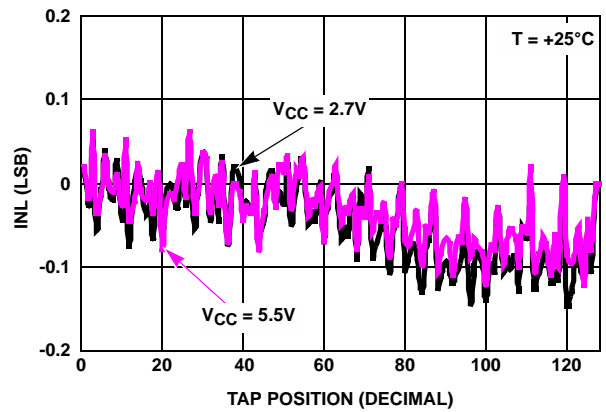FIGURE 3. DNL vs TAP POSITION IN VOLTAGE DIVIDER MODE FOR 10kΩ (W)

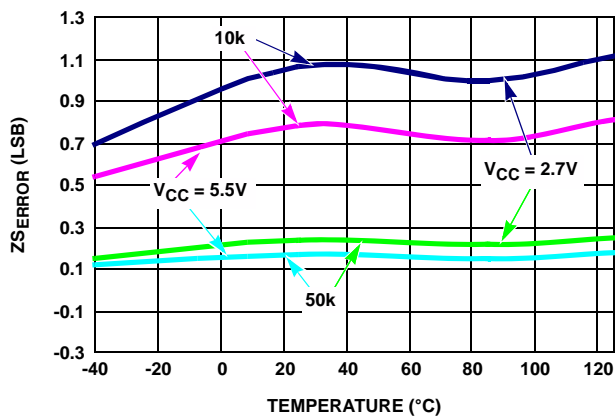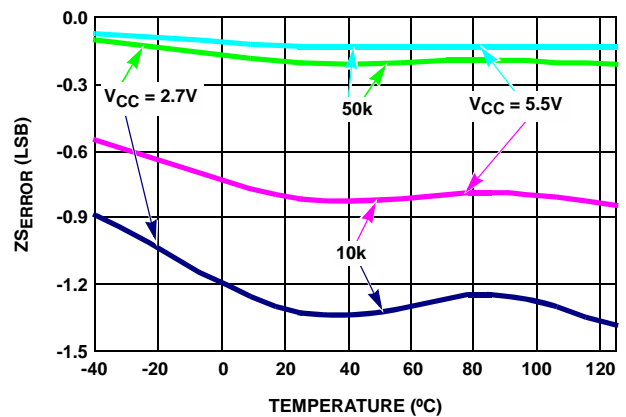FIGURE 4. INL vs TAP POSITION IN VOLTAGE DIVIDER MODE FOR 10kΩ (W)

FIGURE 5. ZS$_{ERROR}$ vs TEMPERATURE

FIGURE 6. FS$_{ERROR}$ vs TEMPERATURE
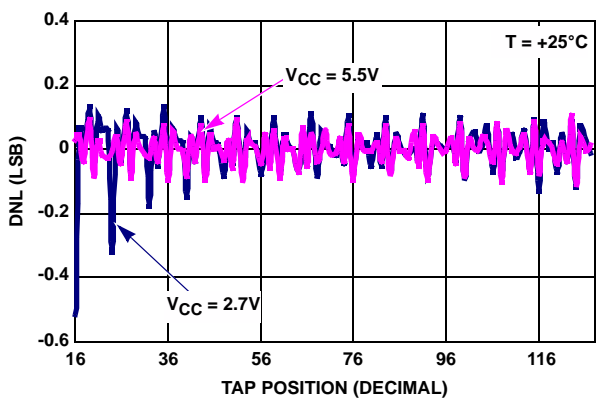
FIGURE 7. DNL vs TAP POSITION IN RHEOSTAT MODE FOR 10kΩ (W)
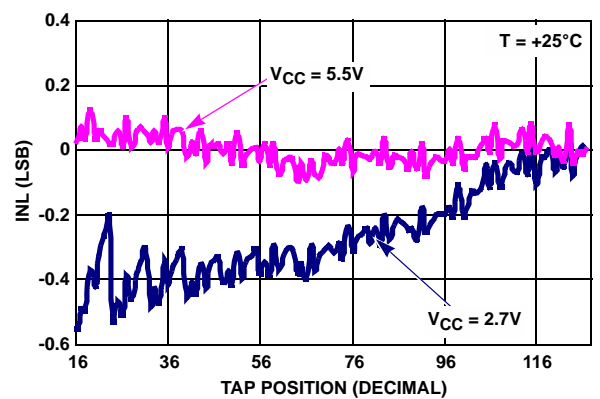
FIGURE 8. INL vs TAP POSITION IN RHEOSTAT MODE FOR 10kΩ (W)

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Typical Performance Curves (Continued)
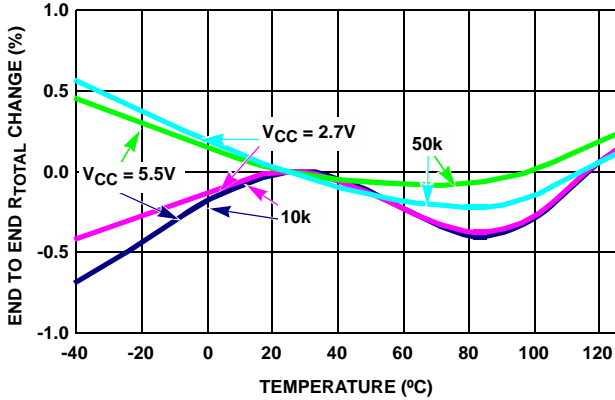
FIGURE 9. END TO END R_{TOTAL} % CHANGE vs TEMPERATURE
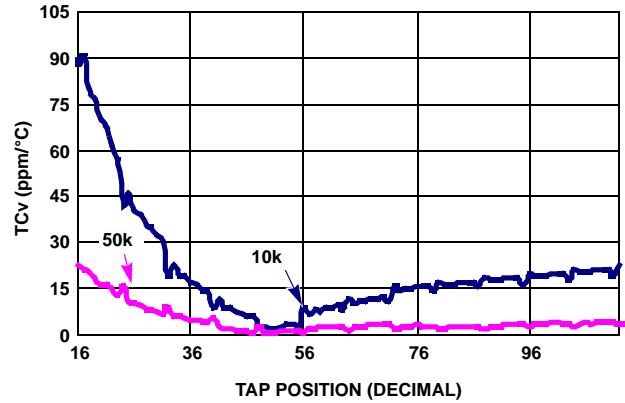
FIGURE 10. TC FOR VOLTAGE DIVIDER MODE IN ppm
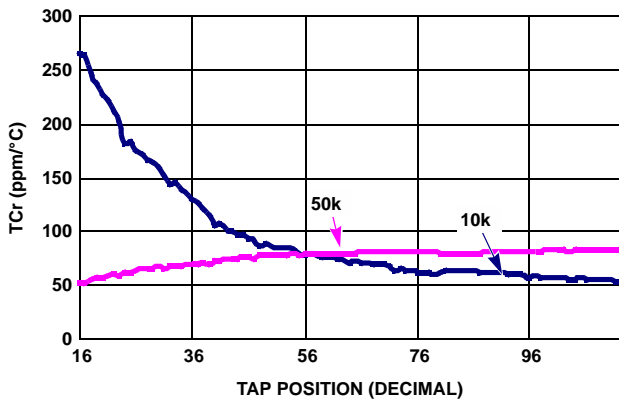
FIGURE 11. TC FOR RHEOSTAT MODE IN ppm
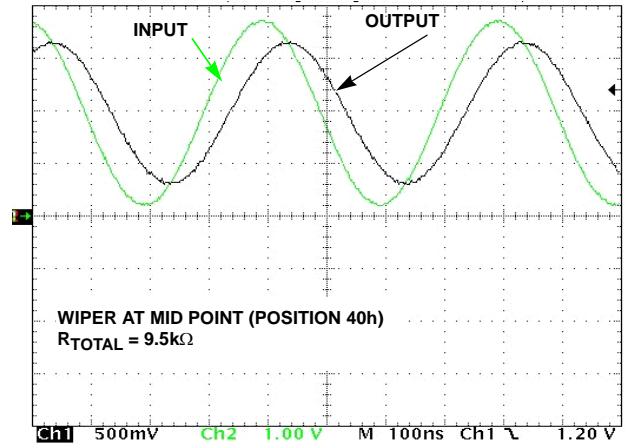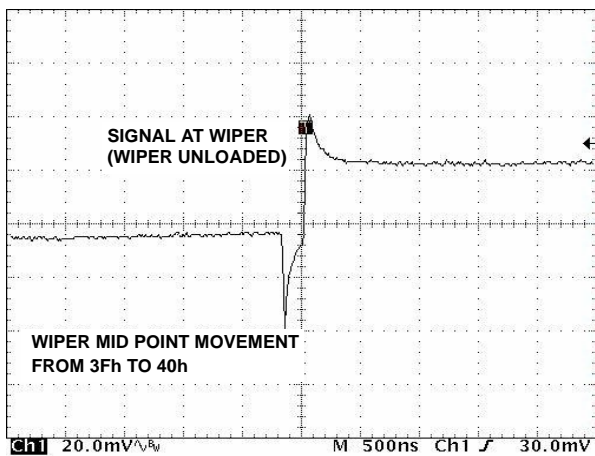

FIGURE 12. FREQUENCY RESPONSE (2.6MHz)
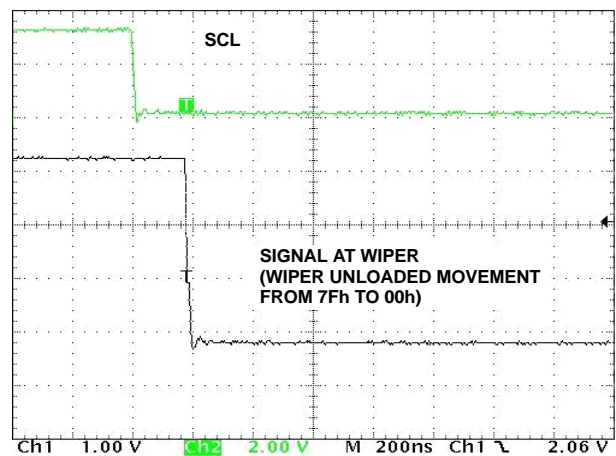

FIGURE 13. MIDSCALE GLITCH, CODE 3Fh TO 40h

FIGURE 14. LARGE SIGNAL SETTLING TIME

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Pin Descriptions

Potentiometers Pins

RHI AND RLI (i = 0, 1, 2 OR 3)

The high (RHi) and low (RLi) terminals of the ISL22346 are equivalent to the fixed terminals of a mechanical potentiometer. RHi and RLi are referenced to the relative position of the wiper and not the voltage potential on the terminals. With WRi set to 127 decimal, the wiper will be closest to RHi, and with the WRi set to 0, the wiper is closest to RLi.

RWI (i = 0, 1, 2 OR 3)

RWi is the wiper terminal and is equivalent to the movable terminal of a mechanical potentiometer. The position of the wiper within the array is determined by the WRi register.

$\overline{SHDN}$

The $\overline{SHDN}$ pin forces the resistor to end-to-end open circuit condition on RHi and shorts RWi to RLi. When $\overline{SHDN}$ is returned to logic high, the previous latch settings put RWi at the same resistance setting prior to shutdown. This pin is logically ANDed with SHDN bit in ACR register. I^{2}C interface is still available in shutdown mode and all registers are accessible. This pin must remain HIGH for normal operation.
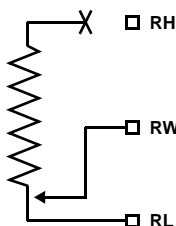

FIGURE 15. DCP CONNECTION IN SHUTDOWN MODE

Bus Interface Pins

SERIAL DATA INPUT/OUTPUT (SDA)

The SDA is a bidirectional serial data input/output pin for I^{2}C interface. It receives device address, operation code, wiper address and data from an I^{2}C external master device at the rising edge of the serial clock SCL, and it shifts out data after each falling edge of the serial clock.

SDA requires an external pull-up resistor, since it is an open drain input/output.

SERIAL CLOCK (SCL)

This is the serial clock input of the I^{2}C serial interface. SCL requires an external pull-up resistor, since it is an open drain input.

DEVICE ADDRESS (A2 - A0)

The address inputs are used to set the least significant 3 bits of the 7-bit I^{2}C interface slave address. A match in the slave address serial data stream must match with the Address

input pins in order to initiate communication with the ISL22346. A maximum of 8 ISL22346 devices may occupy the I^{2}C serial bus.

Principles of Operation

The ISL22346 is an integrated circuit incorporating four DCPs with their associated registers, non-volatile memory and an I^{2}C serial interface providing direct communication between a host and the potentiometers and memory. The resistor arrays are comprised of individual resistors connected in series. At either end of the array and between each resistor is an electronic switch that transfers the potential at that point to the wiper.

The electronic switches on the device operate in a "make before break" mode when the wiper changes tap positions.

When the device is powered down, the last value stored in IVRi will be maintained in the non-volatile memory. When power is restored, the contents of the IVRi are recalled and loaded into the corresponding WRi to set the wipers to the initial value.

DCP Description

Each DCP is implemented with a combination of resistor elements and CMOS switches. The physical ends of each DCP are equivalent to the fixed terminals of a mechanical potentiometer (RH and RL pins). The RW pin of each DCP is connected to intermediate nodes, and is equivalent to the wiper terminal of a mechanical potentiometer. The position of the wiper terminal within the DCP is controlled by volatile Wiper Register (WR). Each DCP has its own WR. When the WR of a DCP contains all zeroes (WR[6:0]= 00h), its wiper terminal (RW) is closest to its "Low" terminal (RL). When the WR register of a DCP contains all ones (WR[6:0]= 7Fh), its wiper terminal (RW) is closest to its "High" terminal (RH). As the value of the WR increases from all zeroes (0) to all ones (127 decimal), the wiper moves monotonically from the position closest to RL to the closest to RH. At the same time, the resistance between RW and RL increases monotonically, while the resistance between RH and RW decreases monotonically.

While the ISL22346 is being powered up, all four WRs are reset to 40h (64 decimal), which locates RW roughly at the center between RL and RH. After the power supply voltage becomes large enough for reliable non-volatile memory reading, all WRs will be reload with the value stored in corresponding non-volatile Initial Value Registers (IVRs).

The WRs can be read or written to directly using the I^{2}C serial interface as described in the following sections. The I^{2}C interface Address Byte has to be set to 00h, 01h, 02h or 03h to access the WR of DCP0, DCP1, DCP2 or DCP3 respectively.

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Memory Description

The ISL22346 contains seven non-volatile and five volatile 8-bit registers. The memory map of ISL22346 is on Table 1. The four non-volatile registers (IVRi) at address 0, 1, 2 and 3 contain initial wiper value and volatile registers (WRi) contain current wiper position. In addition, three non-volatile General Purpose registers from address 4 to address 6 are available.

TABLE 1. MEMORY MAP

ADDRESS	NON-VOLATILE	VOLATILE
8	—	ACR
7	Reserved	
6	General Purpose	Not Available
5	General Purpose	Not Available
4	General Purpose	Not Available
3	IVR3	WR3
2	IVR2	WR2
1	IVR1	WR1
0	IVR0	WR0

The non-volatile IVRi and volatile WRi registers are accessible with the same address.

The Access Control Register (ACR) contains information and control bits described in Table 2. The VOL bit at access control register (ACR[7]) determines whether the access is to wiper registers WRi or initial value registers IVRi.

TABLE 2. ACCESS CONTROL REGISTER (ACR)

VOL	SHDN	WIP	0	0	0	0	0

If VOL bit is 0, the non-volatile IVRi registers are accessible. If VOL bit is 1, only the volatile WRi are accessible. Note, value is written to IVRi register also is written to the corresponding WRi. The default value of this bit is 0.

The SHDN bit (ACR[6]) disables or enables Shutdown mode. This bit is logically ANDed with $\overline{SHDN}$ pin. When this bit is 0, all DCPs are in Shutdown mode. Default value of SHDN bit is 1.

The WIP bit (ACR[5]) is read only bit. It indicates that non-volatile write operation is in progress. It is impossible to write to the WRi or ACR while WIP bit is 1.

Shutdown Mode

The device can be put in Shutdown mode either by pulling the $\overline{SHDN}$ pin to GND or setting the SHDN bit in the ACR register to 0. The truth table for Shutdown mode is in Table 3.

TABLE 3.

$\overline{SHDN}$ pin	SHDN bit	Mode
High	1	Normal operation
Low	1	Shutdown
High	0	Shutdown
Low	0	Shutdown

I²C Serial Interface

The ISL22346 supports an I²C bidirectional bus oriented protocol. The protocol defines any device that sends data onto the bus as a transmitter and the receiving device as the receiver. The device controlling the transfer is a master and the device being controlled is the slave. The master always initiates data transfers and provides the clock for both transmit and receive operations. Therefore, the ISL22346 operates as a slave device in all applications.

All communication over the I²C interface is conducted by sending the MSB of each byte of data first.

Protocol Conventions

Data states on the SDA line must change only during SCL LOW periods. SDA state changes during SCL HIGH are reserved for indicating START and STOP conditions (see Figure 16). On power-up of the ISL22346, the SDA pin is in the input mode.

All I²C interface operations must begin with a START condition, which is a HIGH to LOW transition of SDA while SCL is HIGH. The ISL22346 continuously monitors the SDA and SCL lines for the START condition and does not respond to any command until this condition is met (see Figure 16). A START condition is ignored during the power-up of the device.

All I²C interface operations must be terminated by a STOP condition, which is a LOW to HIGH transition of SDA while SCL is HIGH (see Figure 16). A STOP condition at the end of a read operation, or at the end of a write operation places the device in its standby mode.

An ACK, Acknowledge, is a software convention used to indicate a successful data transfer. The transmitting device, either master or slave, releases the SDA bus after transmitting eight bits. During the ninth clock cycle, the receiver pulls the SDA line LOW to acknowledge the reception of the eight bits of data (see Figure 17).

The ISL22346 responds with an ACK after recognition of a START condition followed by a valid Identification Byte, and once again after successful receipt of an Address Byte. The ISL22346 also responds with an ACK after receiving a Data Byte of a write operation. The master must respond with an ACK after receiving a Data Byte of a read operation.

A valid Identification Byte contains 1010 as the four MSBs, and the following three bits matching the logic values present at pins A2, A1, and A0. The LSB is the Read/$\overline{Write}$ bit. Its value is "1" for a Read operation, and "0" for a Write operation (see Table 4).

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TABLE 4. IDENTIFICATION BYTE FORMAT

Logic values at pins A2, A1, and A0 respectively

1	0	1	0	A2	A1	A0	R/$\overline{W}$

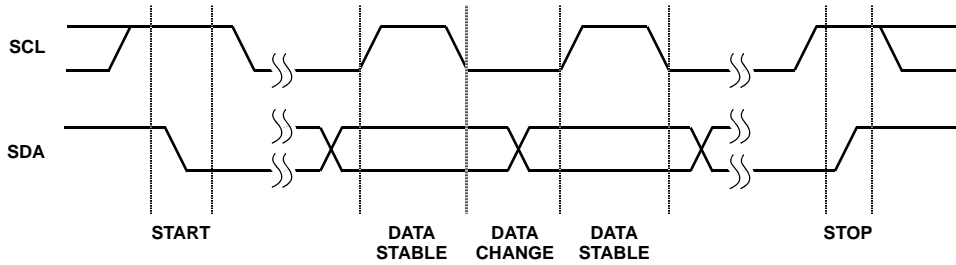(MSB)   (LSB)

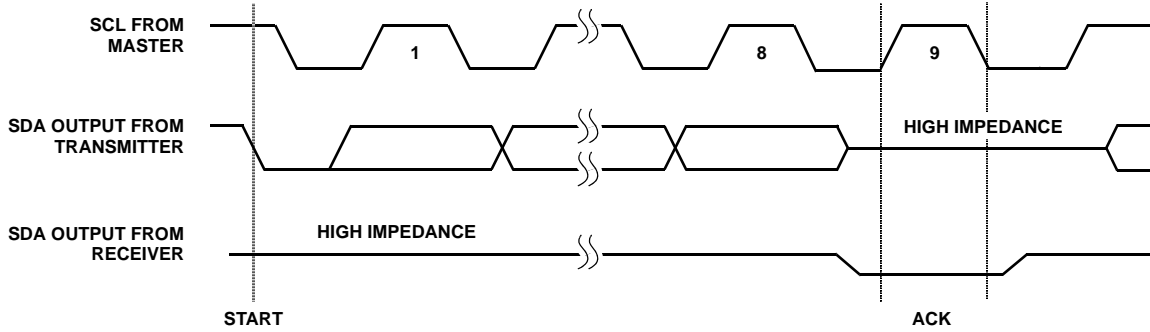**FIGURE 16. VALID DATA CHANGES, START AND STOP CONDITIONS**
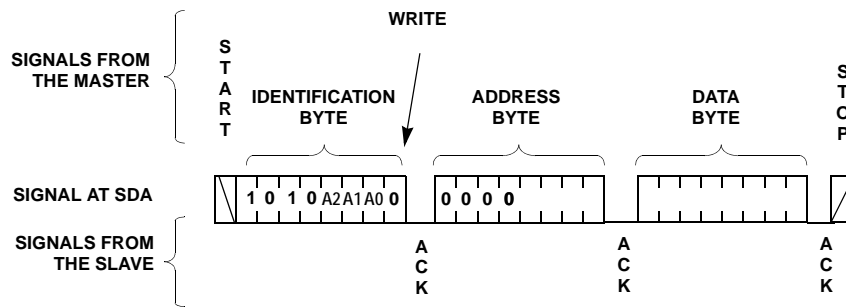

FIGURE 17. ACKNOWLEDGE RESPONSE FROM RECEIVER
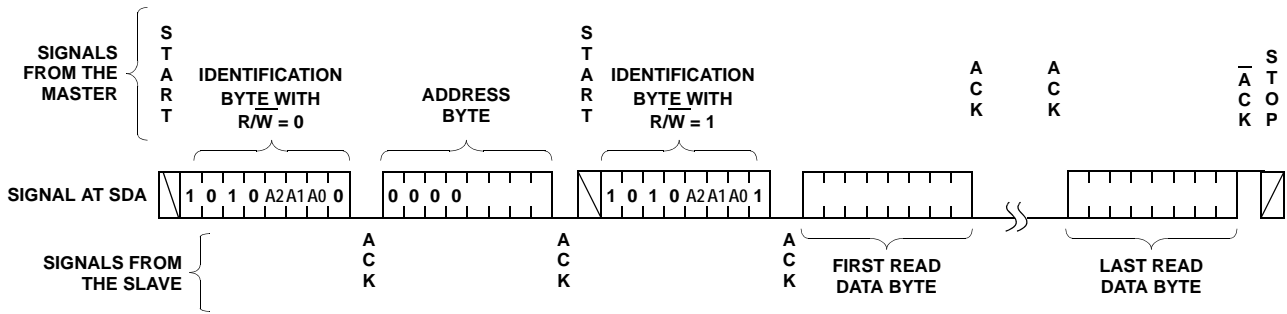

FIGURE 18. BYTE WRITE SEQUENCE

ISL22346

FIGURE 19. READ SEQUENCE

Write Operation

A Write operation requires a START condition, followed by a valid Identification Byte, a valid Address Byte, a Data Byte, and a STOP condition. After each of the three bytes, the ISL22346 responds with an ACK. At this time, the device enters its standby state (see Figure 18). Device can receive more than one byte of data by auto incrementing the address after each received byte. Note after reaching the address 08h, the internal pointer "rolls over" to address 00h. The non-volatile write cycle starts after STOP condition is determined and it requires up to 20ms delay for the next non-volatile write. Thus, non-volatile registers must be written individually.

Read Operation

A Read operation consist of a three byte instruction followed by one or more Data Bytes (See Figure 19). The master initiates the operation issuing the following sequence: a START, the Identification byte with the R/$\overline{W}$ bit set to "0", an Address Byte, a second START, and a second Identification byte with the R/$\overline{W}$ bit set to "1". After each of the three bytes, the ISL22346 responds with an ACK. Then the ISL22346 transmits Data Bytes as long as the master responds with an ACK during the SCL cycle following the eighth bit of each byte. The master terminates the read operation (issuing a $\overline{ACK}$ and a STOP condition) following the last bit of the last Data Byte (see Figure 19).
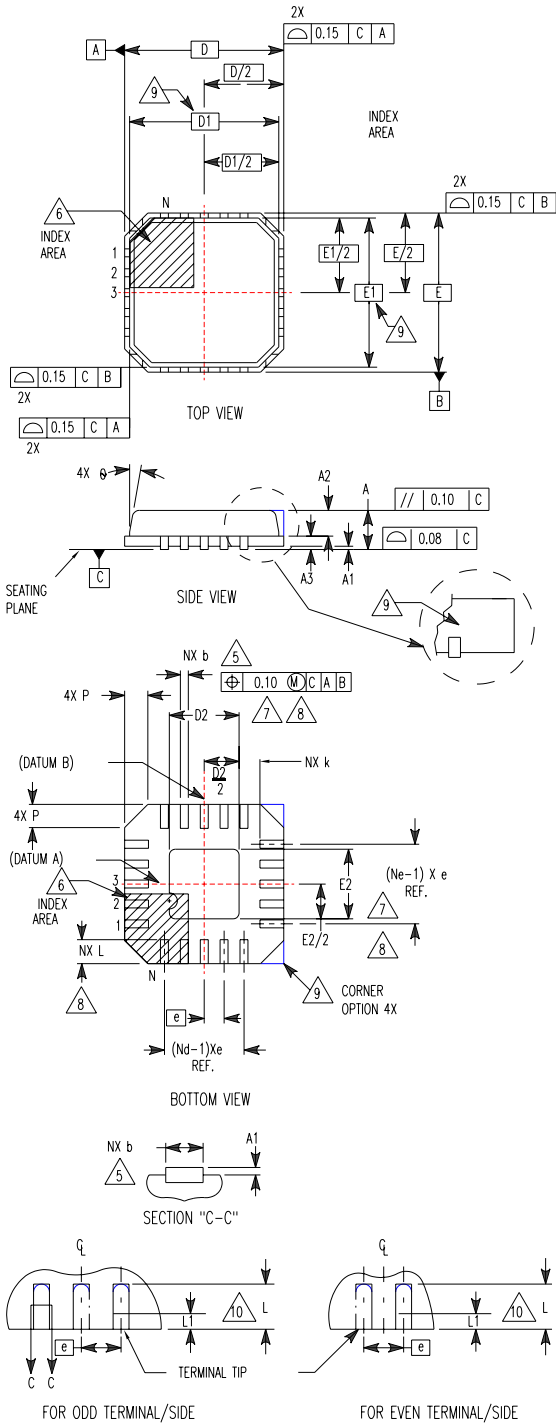
The Data Bytes are from the registers indicated by an internal pointer. This pointer initial value is determined by the Address Byte in the Read operation instruction, and increments by one during transmission of each Data Byte. After reaching the memory location 08h, the pointer "rolls over" to 00h, and the device continues to output data for each ACK received.

In order to read back the non-volatile IVR, it is recommended that the application reads the ACR first to verify the WIP bit is 0. If the WIP bit (ACR[5]) is not 0, the host should repeat its reading sequence again.

ISL22346

Thin Micro Lead FramePlastic Package (TMLFP)

TOP VIEW

SIDE VIEW

BOTTOM VIEW

SECTION "C-C"

FOR ODD TERMINAL/SIDE

FOR EVEN TERMINAL/SIDE

L20.4x4A
20 LEAD QUAD FLAT NO-LEAD PLASTIC PACKAGE (COMPLIANT TO JEDEC MO-220WGGD-1 ISSUE I)

| SYMBOL	MILLIMETERS			NOTES
	MIN	NOMINAL	MAX	
A	0.70	0.75	0.80	-
A1	-	0.02	0.05	-
A2	-	0.55	0.80	9
A3		0.20 REF		9
b	0.18	0.25	0.30	5, 8
D		4.00 BSC		-
D1		3.75 BSC		9
D2	1.95	2.10	2.25	7, 8
E		4.00 BSC		-
E1		3.75 BSC		9
E2	1.95	2.10	2.25	7, 8
e		0.50 BSC		-
k	0.20	-	-	-
L	0.35	0.60	0.75	8
N		20		2
Nd		5		3
Ne		5		3
P	-	-	0.60	9
θ	-	-	12	9

Rev. 0 11/04

NOTES:

1. Dimensioning and tolerancing conform to ASME Y14.5-1994.

2. N is the number of terminals.

3. Nd and Ne refer to the number of terminals on each D and E.

4. All dimensions are in millimeters. Angles are in degrees.

5. Dimension b applies to the metallized terminal and is measured between 0.15mm and 0.30mm from the terminal tip.

6. The configuration of the pin #1 identifier is optional, but must be located within the zone indicated. The pin #1 identifier may be either a mold or mark feature.

7. Dimensions D2 and E2 are for the exposed pads which provide improved electrical and thermal performance.

8. Nominal dimensions are provided to assist with PCB Land Pattern Design efforts, see Intersil Technical Brief TB389.

9. Features and dimensions A2, A3, D1, E1, P & θ are present when Anvil singulation method is used and not present for saw singulation.

ISL22346

Thin Shrink Small Outline Plastic Packages (TSSOP)
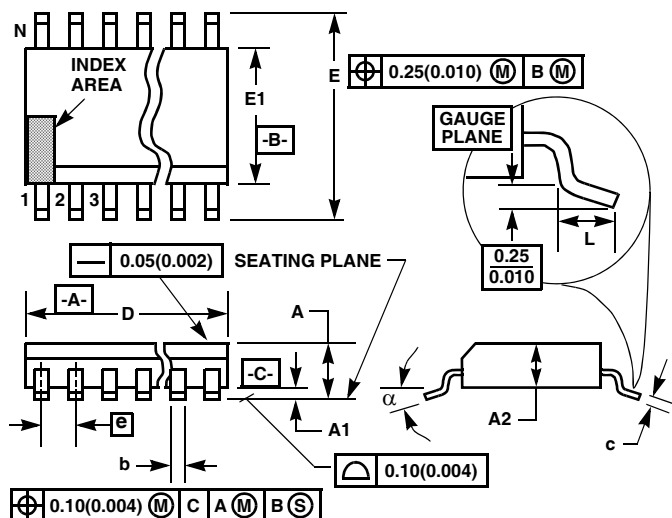
NOTES:

1. These package dimensions are within allowable dimensions of JEDEC MO-153-AC, Issue E.

2. Dimensioning and tolerancing per ANSI Y14.5M-1982.

3. Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion and gate burrs shall not exceed 0.15mm (0.006 inch) per side.

4. Dimension "E1" does not include interlead flash or protrusions. Interlead flash and protrusions shall not exceed 0.15mm (0.006 inch) per side.

5. The chamfer on the body is optional. If it is not present, a visual index feature must be located within the crosshatched area.

6. "L" is the length of terminal for soldering to a substrate.

7. "N" is the number of terminal positions.

8. Terminal numbers are shown for reference only.

9. Dimension "b" does not include dambar protrusion. Allowable dambar protrusion shall be 0.08mm (0.003 inch) total in excess of "b" dimension at maximum material condition. Minimum space between protrusion and adjacent lead is 0.07mm (0.0027 inch).

10. Controlling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact. (Angles in degrees)

M20.173
20 LEAD THIN SHRINK SMALL OUTLINE PLASTIC PACKAGE

SYMBOL	INCHES		MILLIMETERS		NOTES
	MIN	MAX	MIN	MAX	
A	-	0.047	-	1.20	-
A1	0.002	0.006	0.05	0.15	-
A2	0.031	0.051	0.80	1.05	-
b	0.0075	0.0118	0.19	0.30	9
c	0.0035	0.0079	0.09	0.20	-
D	0.252	0.260	6.40	6.60	3
E1	0.169	0.177	4.30	4.50	4
e	0.026 BSC		0.65 BSC		-
E	0.246	0.256	6.25	6.50	-
L	0.0177	0.0295	0.45	0.75	6
N	20		20		7
α	0°	8°	0°	8°	-

Rev. 1 6/98

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